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Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
Between 0.293 inches and 0.357 inches	
Terminal Length:	
Between 1.000 inches and 1.625 inches	
Overall Diameter:	
Between 0.215 inches and 0.235 inches	
Function For Which Designed:	
Transient suppressor	
End Application:	
Offavionics/c 82918	
Joint Electronic Device Engineering Council/jedec/case Out	tline Designation:
Do-13	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
7.9 breakdown voltage, dc	
Current Rating Per Characteristic:	
10.00 milliamperes forward current, average peak	
Power Rating Per Characteristic:	
1.0 watts small-signal input power, common-collector major	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulk	etins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, an	d similar trade publications, reflecting general type data on certain
environmental and performance requirements and test condition	ns that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:	
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/500 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
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